High Efficiency Linear Power Supply with Power Surveillance and Time-out

Features

- Supply voltage monitoring
- Highly accurate 5 V, 100 mA guaranteed output
- Low dropout voltage, typically 380 mV at 100 mA
- Low quiescent current, typically 100 μA
- Standby mode, maximum current 310 μA (with 100 μA load on OUTPUT)
- Unregulated DC input can withstand –20 V reverse battery and + 60 V power transients
- Fully operational for unregulated DC input voltage up to 26 V and regulated output voltage down to 1 V
- Reset output guaranteed for regulated output voltage down to 1 V
- No reverse output current
- Very low temperature coefficient for the regulated output
- Current limiting
- Clear microprocessor restart after power up
- Push-pull or Open drain output
- -40 to +85 °C temperature range
- DIP8 and SO8 packages

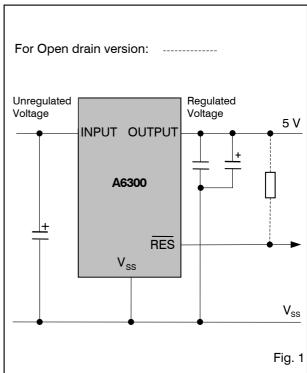
Description

The A6300 offers a high level of integration by combining voltage regulation and voltage monitoring. The voltage regulator has a low dropout (typ. 380 mV at 100 mA) and a low quiescent current (100 μA). The quiescent current increases only slightly in dropout prolonging battery life. Built-in protection includes a positive transient absorber for up to 60 V (load dump) and the ability to survive an unregulated input voltage of -20 V (reverse battery). The INPUT may be connected to ground or a reverse voltage without reverse current flow from the OUTPUT to the INPUT. Upon the OUTPUT voltage rising above V_{TH} , the reset output, whether RES or \overline{RES} , will remain active (RES = 1, \overline{RES} = 0) for an additional time of 50 ms. This allows the system voltage and the oscillator of the microprocessor to stabilize before they becomes fully active. When V_{OUTPUT} falls below V_{TH} , the reset output goes active. Threshold voltage can be obtained in different versions: 2 V, 2.4 V, 2.8 V, 3.5 V, 4 V.

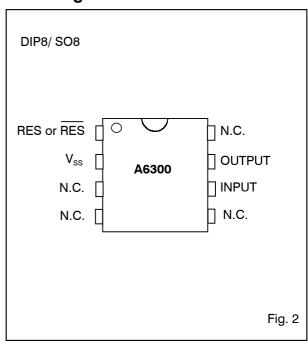
Applications

- White / brown goods
- Industrial electronics
- Automotive electronics
- Cellular telephones
- Security systems
- Battery powered products
- High efficiency linear power supplies

Typical Operating Configuration



Pin Assignment





Absolute Maximum Ratings

Parameter	Symbol	Conditions
Continuous voltage at INPUT		
to V _{SS}	V_{INPUT}	- 0.3 to + 30 V
Transients on INPUT for		
t < 100 ms and duty cycle 1%	V_{TRANS}	up to + 60 V
Reverse supply voltage on INPUT	V_{REV}	- 20 V
Max. voltage at any signal pin	V_{MAX}	OUTPUT + 0.3 V
Min. voltage at any signal pin	V_{MIN}	$V_{SS} - 0.3 V$
Storage temperature	T _{STO}	- 65 to + 150 °C
Electrostatic discharge max. to		
MIL-STD-883C method 3015	V_{Smax}	1000 V
Max. soldering conditions	T _{Smax}	250 °C x 10 s

Table 1

Stresses above these listed maximum ratings may cause permanent damage to the device. Exposure beyond specified operating conditions may affect device reliability or cause malfunction.

Handling Procedures

This device has built-in protection against high static voltages or electric fields; however, anti-static precautions must be taken as for any other CMOS component. Unless otherwise specified, proper operation can only occur when all terminal voltages are kept within the supply voltage range. Unused inputs must always be tied to a defined logic voltage level.

Operating Conditions

Parameter	Symbol	Min.	Тур.	Max.	Units
Operating junction					
temperature 1)	T_J	-40		+125	°C
INPUT voltage 2)	V_{INPUT}	2.3		26	V
OUTPUT voltage 2)3)	V_{OUTPUT}	1.0			V
Reset output guaranteed	V_{OUTPUT}	1.0			V
OUTPUT current 4)	I _{OUTPUT}			100	mA
Thermal resistance from					
junction to ambient 5)					
- DIP8	$R_{th(j-a)}$			105	°C/W
- SO8	R _{th(j-a)}			160	°C/W

Table 2

- 1) The maximum operating temperature is confirmed by sampling at initial device qualification. In production, all devices are tested at + 85 °C.
- ²⁾ Full operation quaranteed. To achieve the load regulation specified in Table 3 a 22 μF capacitor or greater is required on the INPUT, see Fig. 6. The 22 μF must have an effective resistance \leq 5 Ω and a resonant frequency above 500 kHz.
- $^{3)}$ A 10 $\,\mu F$ load capacitor and a 100 nF decoupling capacitor are required on the regulator OUTPUT for stability. The 10 $\,\mu F$ must have an effective series resistance of $\leq 5~\Omega$ and a resonant frequency above $\,$ 500 kHz.
- ⁴⁾ The OUTPUT current will not apply for all possible combinations of input voltage and output current. Combinations that would require the A6300 to work above the maximum junction temperature (+125 °C) must be avoided.
- ⁵⁾ The thermal resistance specified assumes the package is soldered to a PCB.



Electrical Characteristics

 $V_{\text{INPUT}} = 6.0 \text{ V}, C_{\text{L}} = 10 \ \mu\text{F} + 100 \ n\text{F}, C_{\text{INPUT}} = 22 \ \mu\text{F}, T_{\text{J}} = -40 \ to \ +85 \ ^{\circ}\text{C}, unless otherwise specified}$

Parameter	Symbol	Test Conditions	Min.	Min. 25°C	Тур.	Max. 25°C	Мах.	Unit
Supply current	I _{ss}	Reset output open, I _L = 100 μA			100		310	μΑ
Supply current 1)	I _{ss}	Reset output open, I _L = 100 mA						·
		at $V_{INPUT} = 8.0 \text{ V}$			1.7		4.2	mA
Output voltage	V_{OUTPUT}	$I_L = 100 \mu\text{A}$	4.88				5.12	V
Output voltage	V_{OUTPUT}	100 μ A ≤ I_L ≤ 100 mA,						
		-40 °C ≤ T _J ≤+125 °C	4.85				5.15	V
Output voltage temperature								
coefficient 2)	$V_{th(coeff)}$				50		180	ppm/°C
Line regulation 3)	V_{LINE}	$6 \text{ V} \le \text{V}_{\text{INPUT}} \le 26 \text{ V}, \text{ I}_{\text{L}} = 1 \text{ mA},$						
		T _J = +125 °C			0.2		0.5	%
Load regulation 3)	V_L	$100 \mu A \le I_L \le 100 \text{ mA}$			0.2		0.6	%
Dropout voltage 4)	$V_{DROPOUT}$	$I_L = 100 \mu\text{A}$			40		170	mV
Dropout voltage 4)	$V_{DROPOUT}$	$I_L = 100 \text{ mA}$			380			mV
Dropout voltage 4)	$V_{DROPOUT}$	$I_{L} = 100 \text{ mA},$						
		-40 °C ≤ T _J ≤+125 °C					650	mV
Dropout supply current	I _{ss}	$V_{INPUT} = 4.5 \text{ V}, I_L = 100 \mu\text{A}^{-8}$			1.2		1.6	mA
Thermal regulation 5)	V_{thr}	$T_J = +25 ^{\circ}\text{C}, I_L = 50 \text{mA},$						
	١.	$V_{INPUT} = 26 \text{ V}, T = 10 \text{ ms}$			0.05		0.25	%/W
Current limit	I _{Lmax}	OUTPUT tied to V _{ss}			450			mA
OUTPUT noise, 10Hz to	.,							
100 kHz	V _{NOISE}	l.,			200		- · -	μVrms
Threshold voltage	V _{TH}	Version: AA, AG, AM	1.77	1.84	1.95	2.04	2.17	V
	V _{TH}	Version: AB, AH, AN	2.09	2.18	2.32	2.41	2.55	V
	V _{TH}	Version: AC, AI, AO	2.48	2.59	2.73	2.86	3.03	V
	V _{TH}	Version: AD, AJ, AP	3.11	3.23	3.42	3.59	3.80	V
Thursday and by sate used a	V _{TH}	Version: AE, AK, AQ	3.55	3.70	3.88	4.08	4.32	
Threshold hysteresis	V _{HYS}	V 5 V 1 0 A			25		400	mV
RES Output Low Level	V _{OL}	$V_{OUTPUT} = 5 \text{ V}, I_{OL} = 8 \text{ mA}$			175		300	mV
	V _{OL}	$V_{OUTPUT} = 3 \text{ V}, I_{OL} = 4 \text{ mA}$			140			mV
DES Output High Lovel 7)	V _{OL}	$V_{OUTPUT} = 1 \text{ V, } I_{OL} = 50 \mu\text{A}$	4.3		20 4.5		90	mV V
RES Output High Level 7)	V _{OH}	$V_{OUTPUT} = 5 \text{ V}, I_{OH} = -8 \text{ mA}$	2.3					V
	V _{OH}	$V_{OUTPUT} = 3 \text{ V, } I_{OH} = -4 \text{ mA}$			2.6			
Lookago current ⁶⁾	V _{OH}	$V_{OUTPUT} = 1 \text{ V}, I_{OH} = -100 \mu\text{A}$	850		950 0.05		1	mV ^
Leakage current 6)	I _{LEAK}	$V_{OUTPUT} = 5 V$			0.05		ı	μΑ

Table 3

 $^{^{1)}}$ If INPUT is connected to V_{SS} , no reverse current will flow from the OUTPUT to the INPUT, however the supply current specified will be sank by the OUTPUT to supply the A6300.

²⁾ The OUTPUT voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

³⁾ Regulation is measured at constant junction temperature using pulse testing with a low duty cycle. Changes in OUTPUT voltage due to heating effects are covered in the specification for thermal regulation.

⁴⁾ The dropout voltage is defined as the INPUT to OUTPUT differential, measured with the input voltage equal to 5.0 V.

⁵⁾ Thermal regulation is defined as the change in OUTPUT voltage at a time T after a change in power dissipation is applied, excluding load or line regulation effects.

⁶⁾ Only for open drain versions.

⁷⁾ For push-pull output only

⁸⁾ Reset output open



Timing Characteristics

V $_{OUTPUT} = 5.0$ V, $C_L = 10~\mu F + 100$ nF, $C_{INPUT} = 22~\mu F$, $T_J = -40$ to $+~85~^{\circ}C$, unless otherwise specified

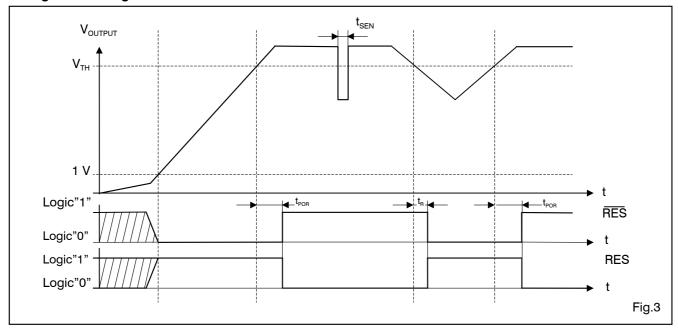
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Power-on Reset time	t _{POR}		25	50	75	ms
Sensitivity 1)	t _{SEN}	$V_{OUTPUT} = 5 V \text{ to } 3 V \text{ in } 5 \mu \text{s}$	20	0.8*t _R		μS
Propagation time 1)	t _R	$V_{OUTPUT} = 5 V \text{ to } 3 V \text{ in } 5 \mu \text{s}$	22	75	200	μS

 $^{^{\}rm 1)}$ Tested on version with $\rm V_{TH}$ higher than 3 $\rm V$

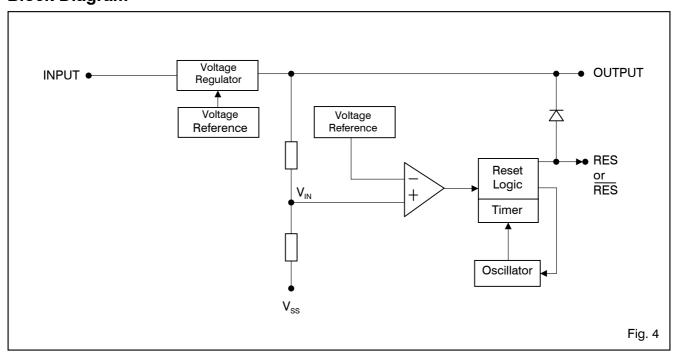
Table 4

Timing Waveforms

Voltage Monitoring



Block Diagram





Pin Description

Pin	Name	Function
1	RES or RES	Reset output
2	V_{ss}	Supply ground
3	N.C.	Not connected
4	N.C.	Not connected
5	N.C.	Not connected
6	INPUT	Unregulated positive supply
7	OUTPUT	Regulated output
8	N.C.	Not connected

Table 5

Functional Description

Voltage Regulator

The A6300 has a 5 V \pm 2%, 100 mA, low dropout voltage regulator. The low supply current (typ.100 μA) makes the A6300 particularly suited to automotive systems then remain energized 24 hours a day. The input voltage range is 2.3 V to 26 V for operation and the input protection includes both reverse battery (20 V below ground) and load dump (positive transients up to 60 V). There is no reverse current flow from the OUTPUT to the INPUT when the INPUT equals $V_{\mbox{\scriptsize SS}}$.This feature is important for systems which need to implement (with capacitance) a minimum power supply hold-up time in the event of power failure. To achieve good load regulation a 22 μF capacitor (or greater) is needed on the INPUT (see Fig. 5). Tantalum or aluminium electrolytics are adequate for the 22 µF capacitor; film types will work but are relatively expensive. Many aluminium electrolytics have electrolytes that freeze at about -30 °C, so tantalums are recommended for operation below –25 $^{\circ}\text{C}.$ The important parameters of the 22 µF capacitor are an effective series resistance of \leq 5 Ω and a resonant frequency above 500 kHz.

A 10 μF capacitor (or greater) and a 100 nF capacitor are required on the OUTPUT to prevent oscillations due to instability. The specification of the 10 μF capacitor is as per the 22 μF capacitor on the INPUT (see previous paragraph).

The A6300 will remain stable and in regulation with no external load and the dropout voltage is typically constant as the input voltage fall to below its minimum level (see Table 2). These features are especially important in CMOS RAM keep-alive applications.

Voltage Monitoring

The power-on reset and the power-down reset are generated internally with a voltage comparison of the voltage reference and the resistor divider (see Fig.4).

At power-up the reset output (RES) is <u>held</u> low (see Fig. 3). After OUTPUT reaches V $_{\rm TH}$, the RES output is held low for an additional power-on-reset (POR) delay t $_{\rm POR}$ (typically 50 ms).The <u>power-on reset</u> delay prevents repeated toggling of RES even if V $_{\rm OUTPUT}$ and the INPUT voltage drops out and recovers. The POR delay allows the microprocessor's crystal oscillator time to stabilize and to ensure correct recognition of the reset signal to the microprocessor.

The RES output goes active low generating the power-down reset whenever V_{OUTPUT} falls below V_{TH} . The sensitivity or reaction time of the internal comparator to the voltage level on V_{IN} is typically 70 μ s.

Temperature Consideration

Care must be taken not to exceed the maximum junction temperature (+ 125 °C). The power dissipation within the A6300 is given by the formula:

$$T_{TOTAL} = (V_{INPUT} - V_{OUTPUT}) * I_{OUTPUT} + (V_{INPUT}) * I_{SS}$$

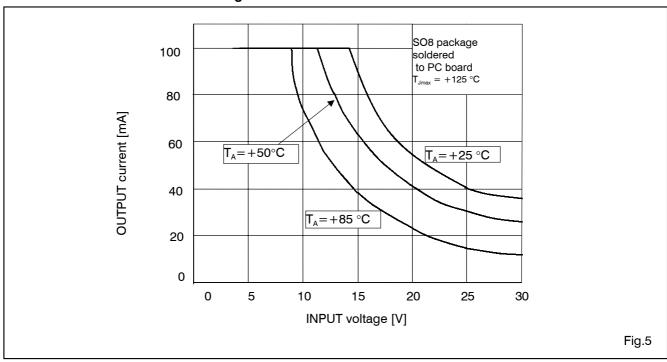
The maximum continuous power dissipation at a given temperature can be calculated using the formula:

$$P_{\text{max}} = (125 \, {}^{\circ}\text{C} - T_{\text{A}}) \, / \, R_{\text{th(j-a)}}$$

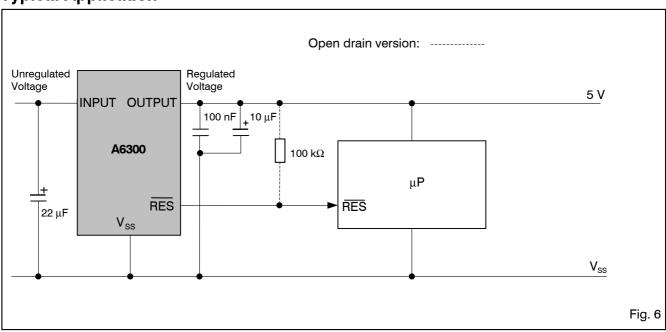
where $R_{th(j-a)}$ is the termal resistance from the junction to the ambient and is specified in Table 2. Note the $R_{th(j-a)}$ given in Table 2 assumes that the package is soldered to a PCB. The above formula for maximum power dissipation assumes a constant load(i.e. $\geq 100~\text{s}$). The transient thermal resistance for a single pulse is much lower than the continuous value. For example the A6300 in DIP8 package will have an effective thermal resistance from the junction to the ambient of about 10 °C/W for a single 100 ms pulse.



OUTPUT Current versus INPUT Voltage



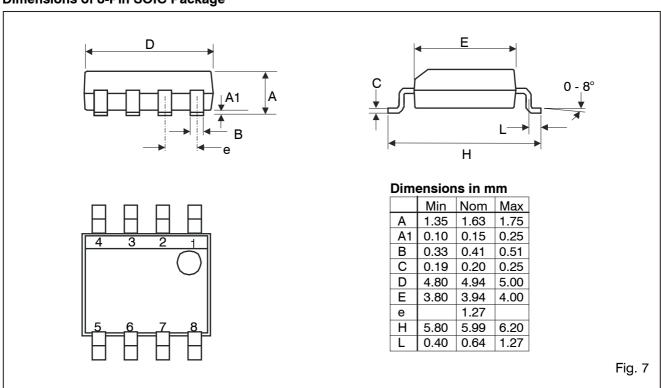
Typical Application



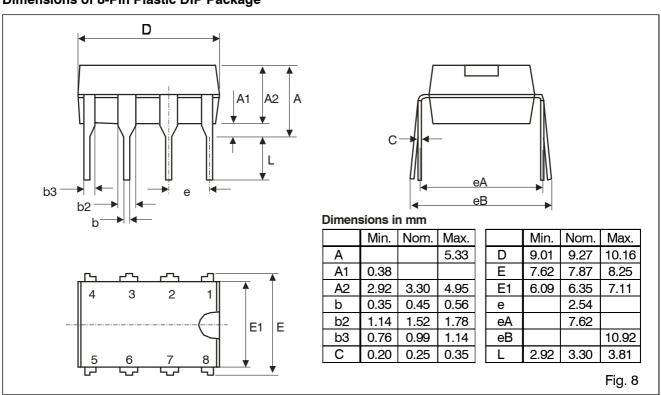


Package Information

Dimensions of 8-Pin SOIC Package



Dimensions of 8-Pin Plastic DIP Package





Ordering Information

Part Number: A6300 AQ SO8A

Threshold Voltage & Output Type

Package & Delivery Form

SO8B = 8-pin SOIC, Tape & Reel SO8A = 8-pin SOIC, Stick DL8A = 8-pin plastic DIP, Stick

	2.0V	2.4V	2.8V	3.5V	4.0V
Push-pull, Reset active low	AA*	AB*	AC*	AD*	AE*
Push-pull, Reset active high	AG*	AH*	Al*	AJ*	AK*
Open drain, Reset active low	AM*	AN*	AO*	AP	AQ

minimum order quantity (please contact EM Microelectronic).

When ordering, please specify the complete Part Number without space between letters: e.g. A6300AQSO8A, A6300APSO8B, etc

Part Number	Package Marking
A6300%%SO8A	(first line) 6300%%
A6300%%SO8B	6300%%
A6300%%DL8A	6300%%

Where %% refers to the 2 letters for the threshold voltage in Table 6 (AP, AQ, etc.)..

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Table 6
*= non stock item. Might be available on request and upon